

# Tadashi Ogitsu

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/4712289/publications.pdf>

Version: 2024-02-01

23

papers

1,277

citations

471509

17

h-index

610901

24

g-index

25

all docs

25

docs citations

25

times ranked

2295

citing authors

| #  | ARTICLE  | IF   | CITATIONS |
|----|--|------|-----------|
| 1  | Crystallographic Effects of GaN Nanostructures in Photoelectrochemical Reaction. <i>Nano Letters</i> , 2022, 22, 2236-2243.  | 9.1  | 12        |
| 2  | Comparison of ablators for the polar direct drive exploding pusher platform. <i>High Energy Density Physics</i> , 2021, 38, 100928.  | 1.5  | 2         |
| 3  | Development of a photoelectrochemically self-improving Si/GaN photocathode for efficient and durable H <sub>2</sub> production. <i>Nature Materials</i> , 2021, 20, 1130-1135.                               | 27.5 | 49        |
| 4  | Structural motifs and bonding in two families of boron structures predicted at megabar pressures. <i>Physical Review Materials</i> , 2021, 5, .  | 2.4  | 8         |
| 5  | Phase transformation in boron under shock compression. <i>Solid State Sciences</i> , 2020, 108, 106376.  | 3.2  | 5         |
| 6  | Benchmarking boron carbide equation of state using computation and experiment. <i>Physical Review E</i> , 2020, 102, 053203.   | 2.1  | 6         |
| 7  | Modulation of Surface Bonding Topology: Oxygen Bridges on OH-Terminated InP (001). <i>Journal of Physical Chemistry C</i> , 2020, 124, 3196-3203.  | 3.1  | 9         |
| 8  | Long-term stability studies of a semiconductor photoelectrode in three-electrode configuration. <i>Journal of Materials Chemistry A</i> , 2019, 7, 27612-27619.  | 10.3 | 28        |
| 9  | Oxidation-Induced Polymerization of InP Surface and Implications for Optoelectronic Applications. <i>Journal of Physical Chemistry C</i> , 2019, 123, 30893-30902.   | 3.1  | 9         |
| 10 | Optical absorption induced by small polaron formation in transition metal oxides: The case of $\text{Co}_2\text{O}_3$ . <i>Physical Review Materials</i> , 2019, 3, .  | 3.1  | 23        |
| 11 | Integrating Ab Initio Simulations and X-ray Photoelectron Spectroscopy: Toward A Realistic Description of Oxidized Solid/Liquid Interfaces. <i>Journal of Physical Chemistry Letters</i> , 2018, 9, 194-203. | 4.6  | 27        |
| 12 | Theoretical and experimental investigation of the equation of state of boron plasmas. <i>Physical Review E</i> , 2018, 98, 023205.   | 2.1  | 23        |
| 13 | Self-optimizing, highly surface-active layered metal dichalcogenide catalysts for hydrogen evolution. <i>Nature Energy</i> , 2017, 2, .  | 39.5 | 336       |
| 14 | Structure and dynamics of aqueous solutions from PBE-based first-principles molecular dynamics simulations. <i>Journal of Chemical Physics</i> , 2016, 145, 154501.  | 3.0  | 87        |
| 15 | Salt Solutions in Carbon Nanotubes: The Role of Cation- $\pi$ Interactions. <i>Journal of Physical Chemistry C</i> , 2016, 120, 7332-7338.   | 3.1  | 62        |
| 16 | Methods of photoelectrode characterization with high spatial and temporal resolution. <i>Energy and Environmental Science</i> , 2015, 8, 2863-2885.  | 30.8 | 51        |
| 17 | Capacitive charge storage at an electrified interface investigated via direct first-principles simulations. <i>Physical Review B</i> , 2015, 91, .   | 3.2  | 25        |
| 18 | Surface Chemistry of GaP(001) and InP(001) in Contact with Water. <i>Journal of Physical Chemistry C</i> , 2014, 118, 1062-1070.   | 3.1  | 49        |

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|----|--|------|-----------|
| 19 | Hydrogen-Bond Dynamics of Water at the Interface with InP/GaP(001) and the Implications for Photoelectrochemistry. <i>Journal of the American Chemical Society</i> , 2013, 135, 15774-15783. | 13.7 | 76        |
| 20 | $\hat{\imath}^2$ -Rhombohedral Boron: At the Crossroads of the Chemistry of Boron and the Physics of Frustration. <i>Chemical Reviews</i> , 2013, 113, 3425-3449.                            | 47.7 | 177       |
| 21 | Local structural models of complex oxygen- and hydroxyl-rich GaP/InP(001) surfaces. <i>Journal of Chemical Physics</i> , 2012, 136, 064705.  | 3.0  | 28        |
| 22 | Geometrical frustration in an elemental solid: An Ising model to explain the defect structure of $\hat{\imath}^2$ -rhombohedral boron. <i>Physical Review B</i> , 2010, 81, .                | 3.2  | 42        |
| 23 | Imperfect Crystal and Unusual Semiconductor: Boron, a Frustrated Element. <i>Journal of the American Chemical Society</i> , 2009, 131, 1903-1909.  | 13.7 | 114       |